

ROHS

v02.0614

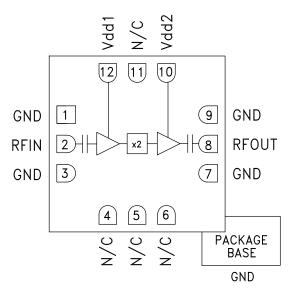
SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 13 - 24.6 GHz OUTPUT

Typical Applications

The HMC814LC3B is ideal for:

- Clock Generation Applications: SONET OC-192 & SDH STM-64
- Point-to-Point & VSAT Radios
- Test Instrumentation
- Military & Space
- Sensors

Functional Diagram



General Description

High Output Power: +17 dBm

Single Supply: +5V @ 88 mA

Low Input Power Drive: 0 to +6 dBm

Fo Isolation: >20 dBc @ Fout = 19 GHz

100 kHz SSB Phase Noise: -136 dBc/Hz

12 Lead 3x3 mm SMT Package: 9 mm²

Features

The HMC814LC3B is a x2 active broadband frequency multiplier utilizing GaAs pHEMT technology in a leadless RoHS compliant SMT package. When driven by a +4 dBm signal, the multiplier provides +17 dBm typical output power from 13 to 24.6 GHz. The Fo, 3Fo and 4Fo isolations are >20 dBc at 19 GHz. The HMC814LC3B is ideal for use in LO multiplier chains for Pt-to-Pt & VSAT Radios yielding reduced parts count vs. traditional approaches. The low additive SSB Phase Noise of -136 dBc/Hz at 100 kHz offset helps maintain good system noise performance. The RoHS packaged HMC814LC3B eliminates the need for wire bonding, and allows the use of surface mount manufacturing techniques.

Electrical Specifications, $T_{A} = +25^{\circ}$ *C, Vdd1, Vdd2* = +5*V,* +4 *dBm Drive Level*

Parameter	Min.	Тур.	Max.	Units
Frequency Range, Input		6.5 - 12.3	6.5 - 12.3	
Frequency Range, Output		13 - 24.6		
Output Power	14	17		dBm
Fo Isolation (with respect to output level)		25		dBc
3Fo Isolation (with respect to output level)		25		dBc
Input Return Loss	4	10		dB
Output Return Loss	6	12		dB
SSB Phase Noise (100 kHz Offset @ Input Frequency = 19 GHz)		-136		dBc/Hz
Supply Current (Idd1 & Idd2)		88	100	mA

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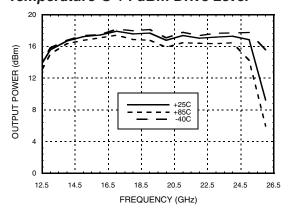


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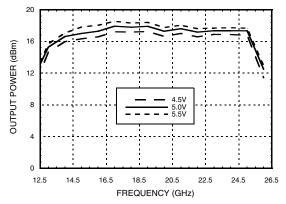
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Output Power vs. Drive Level

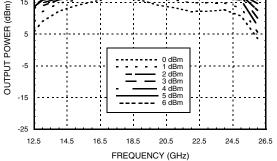
Output Power vs. Temperature @ +4 dBm Drive Level



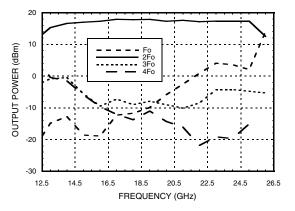
Output Power vs. Supply Voltage @ +4 dBm Drive Level

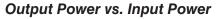


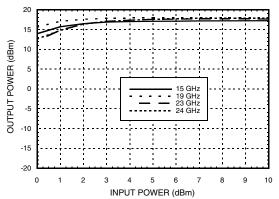




Isolation @ +4 dBm Drive Level







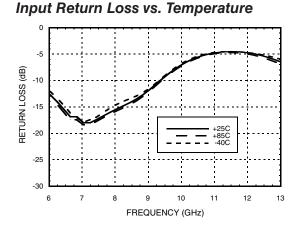
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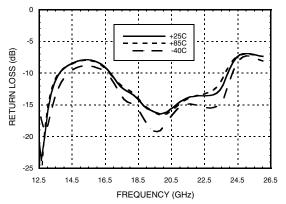


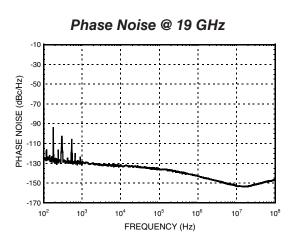
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Output Return Loss vs. Temperature





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SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 13 - 24.6 GHz OUTPUT

Absolute Maximum Ratings

+10 dBm
+5.5 Vdc
175 °C
743 mW
121 °C/W
-65 to +150 °C
-40 to +85 °C
Class 0 (Passed 150 V)

Typical Supply Current vs. Vdd

BOTTOM VIEW

Vdd (Vdc)	ldd (mA)
4.5	87
5.0	88
5.5	89

Note:

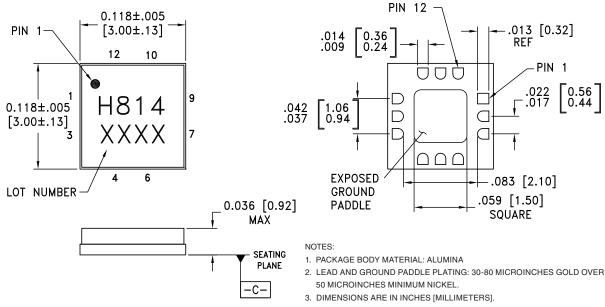
Multiplier will operate over full voltage range shown above.



ELECTROSTATIC SENSITIVE DEVICE **OBSERVE HANDLING PRECAUTIONS**

0.56 0.44

Outline Drawing



4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE

- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]	
HMC814LC3B	Alumina, White	Gold over Nickel	MSL3 ^[1]	H814 XXXX	

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

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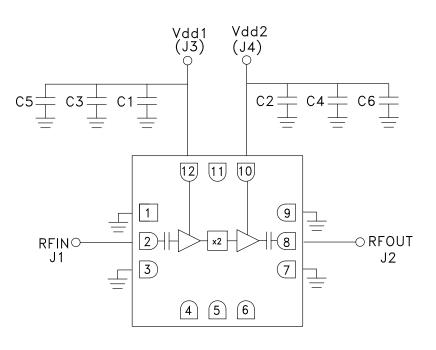
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Pin Description

Pin Number	Function	Description	Interface Schematic
1, 3, 7, 9	GND	Package bottom must also be connected to RF/DC ground.	
2	RFIN	This pin is AC coupled and matched to 50 Ohms.	
4 - 6, 11	N/C	These pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/ DC ground.	
8	RFOUT	This pin is AC coupled and matched to 50 Ohms.	○ RFOUT
10, 12	Vdd2, Vdd1	Supply voltage 5V \pm 0.5V. External bypass capacitors of 100 pF, 1,000 pF and 2.2 μF are recommended.	Vdd1, Vdd2

Application Circuit

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	Component	Value
	C1, C2	100 pF
	C3, C4	1,000 pF
	C5, C6	2.2 µF



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